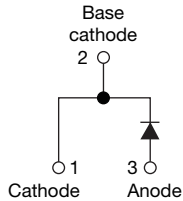


## Hyperfast Rectifier, 15 A FRED Pt®



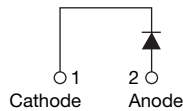
2L TO-220AC



VS-ETH1506-M3



2L TO-220 FULL-PAK



VS-ETH1506FP-M3

### FEATURES

- Hyperfast soft recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ )
- True 2 pin package
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Designed and qualified according to JEDEC-JESD47



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### DESCRIPTION/APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### PRODUCT SUMMARY

Package	2L TO-220AC, 2L TO-220FP
$I_{F(AV)}$	15 A
$V_R$	600 V
$V_F$ at $I_F$	2.45 V
$t_{rr}$ (typ.)	21 ns
$T_J$ max.	175 °C
Diode variation	Single die

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		600	V
Average rectified forward current in DC	$I_{F(AV)}$	$T_C = 149\text{ °C}$	15	A
		$T_C = 94\text{ °C}$		
Non-repetitive peak surge current	$I_{FSM}$	$T_J = 25\text{ °C}$	160	
Operating junction and storage temperatures	$T_J, T_{Stg}$		- 65 to 175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	$V_F$	$I_F = 15\text{ A}$	-	1.8	2.45	
		$I_F = 15\text{ A}, T_J = 150\text{ °C}$	-	1.25	1.6	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	0.01	15	$\mu\text{A}$
		$T_J = 150\text{ °C}, V_R = V_R$ rated	-	20	200	
Junction capacitance	$C_T$	$V_R = 600\text{ V}$	-	12	-	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body	-	8	-	nH

# VS-ETH1506-M3, VS-ETH1506FP-M3



Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®

DYNAMIC RECOVERY CHARACTERISTICS ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Reverse recovery time	$t_{rr}$	$I_F = 1\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	21	26	ns	
		$I_F = 15\text{ A}$ , $di_F/dt = 100\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	25	36		
		$T_J = 25\text{ }^\circ\text{C}$	-	29	-		
		$T_J = 125\text{ }^\circ\text{C}$	-	65	-		
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	3.9	-	A	
		$T_J = 125\text{ }^\circ\text{C}$	-	7.0	-		
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	60	-	nC	
		$T_J = 125\text{ }^\circ\text{C}$	-	240	-		
Reverse recovery time	$t_{rr}$	$T_J = 125\text{ }^\circ\text{C}$	$I_F = 15\text{ A}$ $di_F/dt = 800\text{ A}/\mu\text{s}$ $V_R = 390\text{ V}$	-	42	-	ns
Peak recovery current	$I_{RRM}$			-	21	-	A
Reverse recovery charge	$Q_{rr}$			-	480	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		- 65	-	175	$^\circ\text{C}$
Thermal resistance, junction to case FULL-PAK	$R_{thJC}$		-	1.2	1.4	$^\circ\text{C}/\text{W}$
			-	3.7	4.3	
Thermal resistance, junction to ambient	$R_{thJA}$	Typical socket mount	-	-	70	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, flat, smooth and greased	-	0.5	-	
Weight			-	2	-	g
			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style 2L TO-220AC	ETH1506			
		Case style 2L TO-220 FULL-PAK	ETH1506FP			



# VS-ETH1506-M3, VS-ETH1506FP-M3

Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup> Vishay Semiconductors

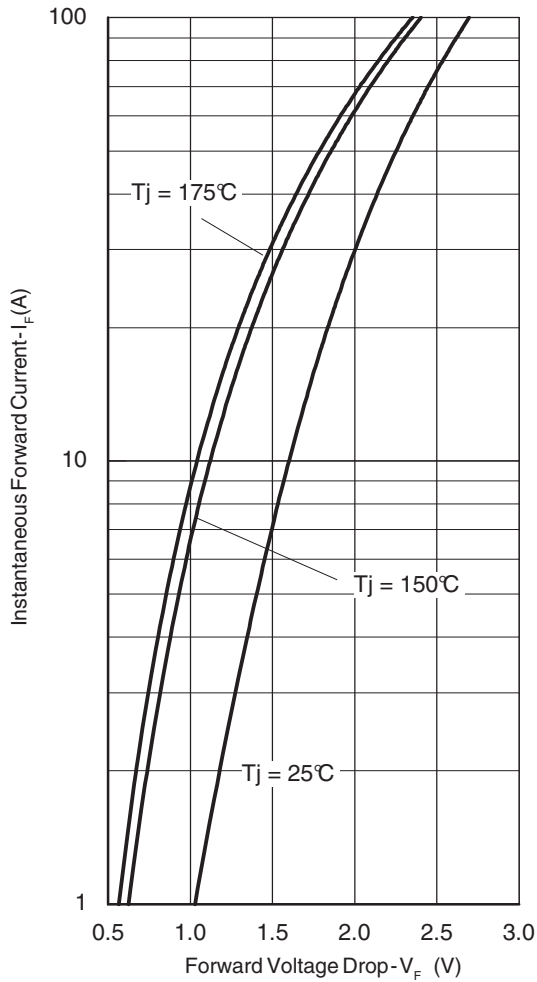


Fig. 1 - Typical Forward Voltage Drop Characteristics

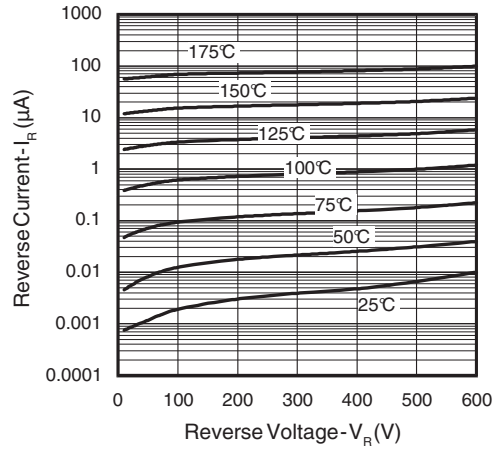


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

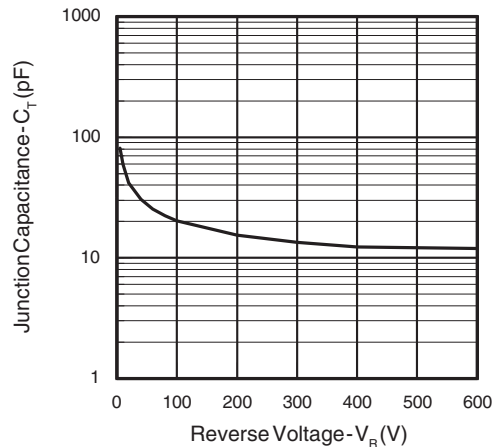


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

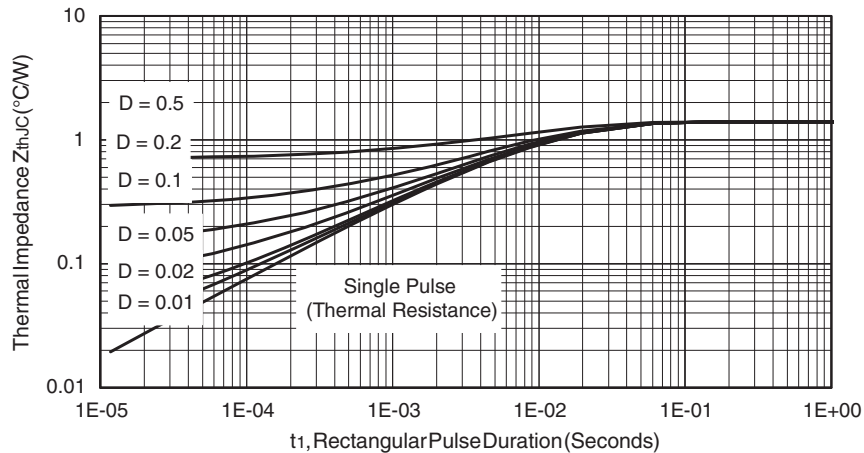


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

# VS-ETH1506-M3, VS-ETH1506FP-M3

Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®

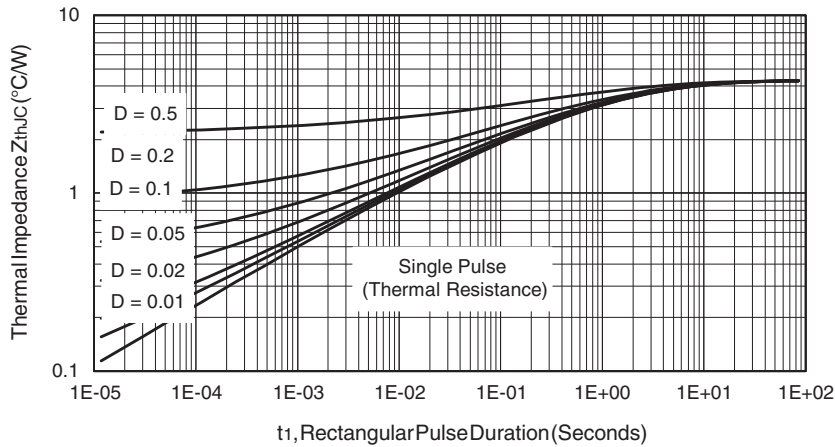


Fig. 5 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (FULL-PAK)

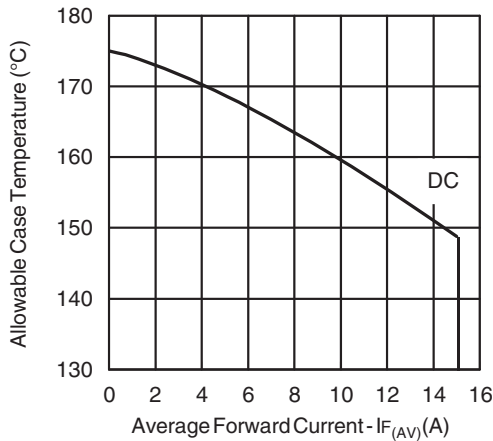


Fig. 6 - Maximum Allowable Case Temperature vs. Average Forward Current

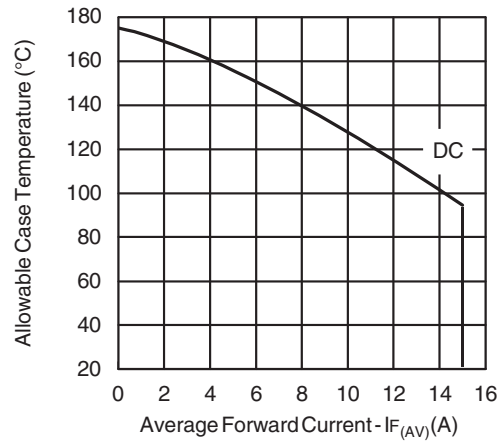


Fig. 7 - Maximum Allowable Case Temperature vs. Average Forward Current (FULL-PAK)

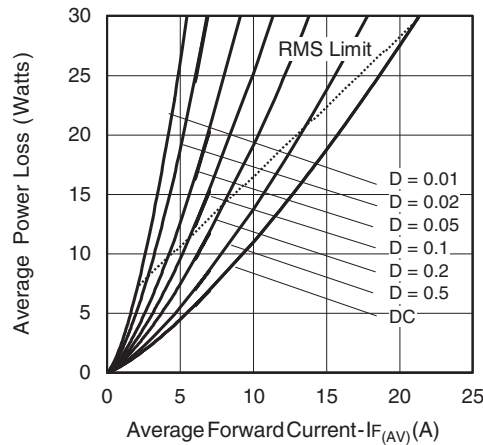


Fig. 8 - Forward Power Loss Characteristics

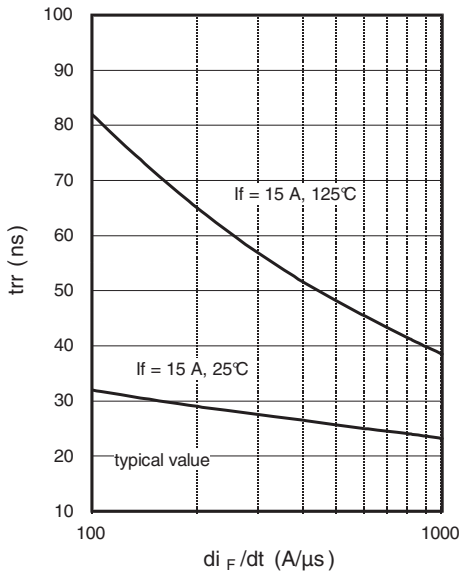


Fig. 9 - Typical Reverse Recovery vs.  $di_F/dt$

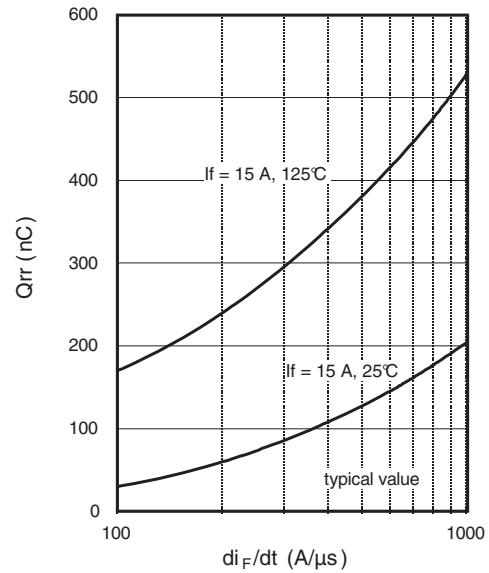
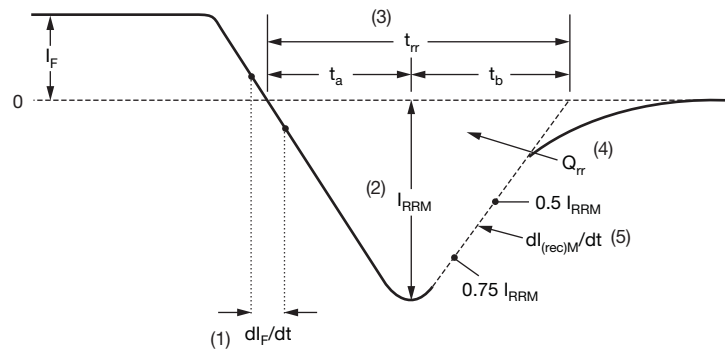


Fig. 10 - Typical Stored Charge vs.  $di_F/dt$



Fig. 11 - Reverse Recovery Parameter Test Circuit



- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.
- (4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 12 - Reverse Recovery Waveform and Definitions

# VS-ETH1506-M3, VS-ETH1506FP-M3

Vishay Semiconductors Hyperfast Rectifier, 15 A FRED Pt®



## ORDERING INFORMATION TABLE

Device code	<b>VS-</b>	<b>E</b>	<b>T</b>	<b>H</b>	<b>15</b>	<b>06</b>	<b>FP</b>	<b>-M3</b>
	①	②	③	④	⑤	⑥	⑦	⑧

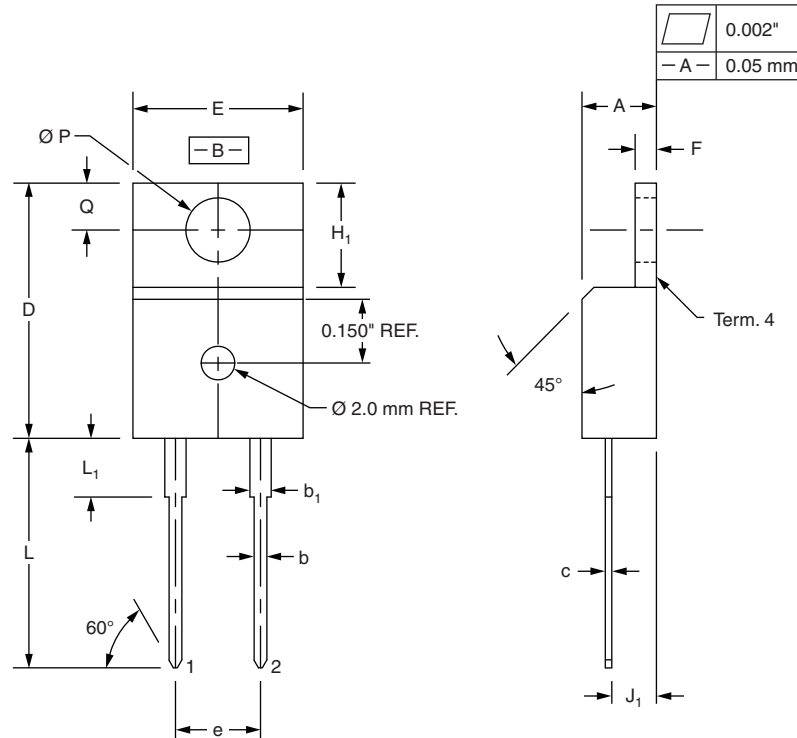
- 1** - Vishay Semiconductors product
- 2** - Circuit configuration:  
E = Single diode
- 3** - T = TO-220
- 4** - H = Hyperfast recovery time
- 5** - Current code: 15 = 15 A
- 6** - Voltage code: 06 = 600 V
- 7** -
  - None = TO-220
  - FP = FULL-PAK
- 8** - Environmental digit:  
-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-ETH1506-M3	50	1000	Antistatic plastic tube
VS-ETH1506FP-M3	50	1000	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS		
Dimensions	2L TO-220AC	<a href="http://www.vishay.com/doc?95259">www.vishay.com/doc?95259</a>
	2L TO-220 FULL-PAK	<a href="http://www.vishay.com/doc?95260">www.vishay.com/doc?95260</a>
Part marking information	2L TO-220AC	<a href="http://www.vishay.com/doc?95391">www.vishay.com/doc?95391</a>
	2L TO-220 FULL-PAK	<a href="http://www.vishay.com/doc?95392">www.vishay.com/doc?95392</a>

### True 2 Pin TO-220

**DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.32	4.57	0.170	0.180
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
c	0.36	0.53	0.014	0.021
D	14.99	15.49	0.590	0.610
E	10.04	10.41	0.395	0.410
e	5.08 BSC		0.200 BSC	
F	1.22	1.37	0.048	0.054
H <sub>1</sub>	5.97	6.47	0.235	0.255
J <sub>1</sub>	2.54	2.79	0.100	0.110
L	13.47	13.97	0.530	0.550
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150
Ø P	3.79	3.88	0.149	0.153
Q	2.60	2.84	0.102	0.112

**Notes**

<sup>(1)</sup> Lead dimension and finish uncontrolled in L<sub>1</sub>

- These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87
- Controlling dimension: Inch



## True 2 Pin TO-220 FULL-PAK

**DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.53	4.93	0.178	0.194
b	0.71	0.91	0.028	0.036
b <sub>1</sub>	1.15	1.39	0.045	0.055
C	0.36	0.53	0.014	0.021
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
e	5.08 typical		0.200 typical	
F	2.34	2.74	0.092	0.107
H <sub>1</sub>	6.50	6.90	0.256	0.272
J <sub>1</sub>	2.56	2.96	0.101	0.117
L	12.78	13.18	0.503	0.519
L <sub>1</sub>	2.23	2.63	0.088	0.104
Ø Q	2.98	3.38	0.117	0.133
Q <sub>1</sub>	3.10	3.50	0.122	0.138
Q <sub>2</sub>	14.80	15.20	0.583	0.598
θ	0°	5°	0°	5°





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**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**

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<http://moschip.ru/get-element>

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